D2528, DECEMBER 1979-REVISED SEPTEMBER 1986

- Output Collector Current . . . 1.5 A Max
- 2-W Dissipation Rating
- High Output-Voltage Capability
- Outputs Diode-Clamped for Inductive Loads
- Common-Emitter Circuit for Current Sink
- ULN2064 and ULN2065 Have TTL Compatible Inputs
- ULN2066 and ULN2067 Have CMOS- and PMOS-Compatible Inputs
- Designed for Interchangeability With Sprague ULN2064 thru ULN2067, Respectively

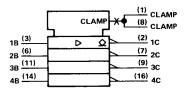
#### description

The ULN2064, ULN2065, ULN2066, and ULN2067 are monolithic high-voltage, highcurrent darlington transistor switches. Each comprises four n-p-n darlington pairs. All units feature high-voltage outputs with commoncathode clamp diodes for switching inductive loads. Outputs and inputs may each be paralleled for higher current capability. Applications include relay drivers, hammer drivers, lamp drivers, display drivers (LED and gas discharge), line drivers, and logic buffers. These commonemitter circuits are designed to operate as current sinks to the load.

The ULN2064 and ULN2065 are intended for use with TTL and 5-V MOS logic. The ULN2066 and ULN2067 are intended for use with PMOS and higher-voltage CMOS logic.

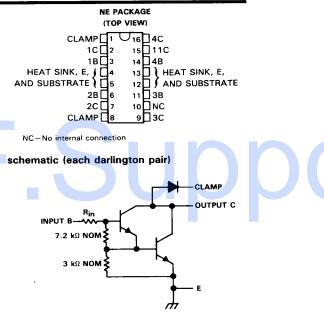
The ULN2064, ULN2065, ULN2066, and ULN2067 are characterized for operation from – 20 °C to 85 °C.

#### logic symbol<sup>†</sup>



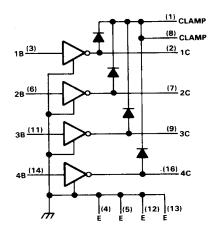
<sup>†</sup>Trus symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

PRODUCTION DATA documents contain information current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



ULN2064, ULN2065:  $R_{in} = 350 \Omega$  NOM ULN2066, ULN2067:  $R_{in} = 3 k\Omega$  NOM

#### logic diagram



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#### absolute maximum ratings at 25 °C free-air temperature for each switch (unless otherwise noted)

	ULN2064	ULN2065	ULN2066	ULN2067	UNIT	
Collector-emitter voltage	50	80	50	80	V	
Input voltage (see Note 1)	15	15	30	30	V	
Peak collector current (see Figures 12, 13, and 14)	1.5	1.5	1.5	1.5	A	
Input current	25	25	25	· 25	mA	
Total power dissipation at (or below) 25 °C free-air temperature (see Note 2)	2075	2075	2075	2075	mW	
Operating free-air temperature range	- 20 to 85	- 20 to 85	-20 to 85	-20 to 85	°C	
Storage temperature range	- 55 to 150	-55 to 150	- 55 to 150	-55 to 150	°C	
Lead temperature 1,6 mm (1/16 inch) from the case for 10 seconds	260	260	260	260	°C	

NOTES: 1. All voltage values (unless otherwise noted) are with respect to the emitter/substrate terminal E.

2. For operation above 25 °C free-air temperature, derate total power linearly to 1079 mW at 85 °C at the rate of 16.6 mW/ °C.

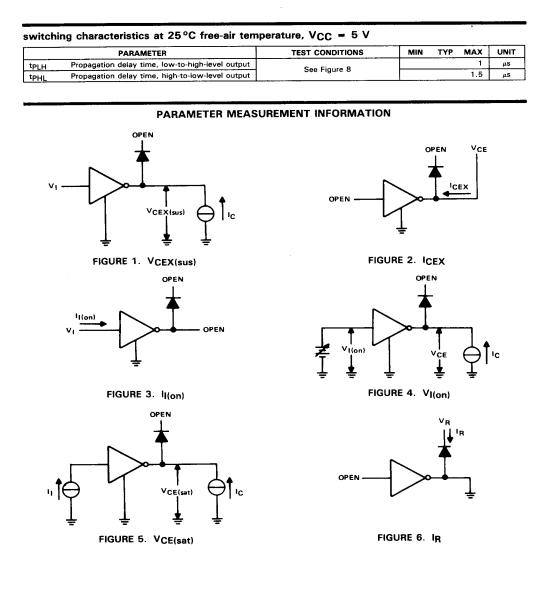
I	PARAMETER	TEST FIGURE	TEST CON	DITIONS		2064 MAX		2065 MAX		2066 MAX	ULN: MIN		UNIT
V <sub>CEX(sus</sub>	Collector sustaining voltage	1	V <sub>I</sub> = 0.4 V,	I <sub>C</sub> = 100 mA	35	•	50		35		50		v
ICEX	Collector output cutoff current	2	$V_{CE} = 50 V$ $V_{CE} = 50 V$ , $V_{CE} = 80 V$ , $V_{CE} = 80 V$ ,			100 500		100		100 500		100 500	μA
ll(on)	On-state input current	3	$V_{1} = 2.4 V$ $V_{1} = 3.75 V$ $V_{1} = 5 V$ $V_{1} = 12 V$		1.4 3.3	4.3 9.6	1.4 3.3	4.3 9.6	0.6	1.8	0.6	1.8	mA
V <sub>I(on)</sub>	On-state input voltage	4	$V_{CE} = 2 V,$ $V_{CE} = 2 V,$ See Note 3	$I_{\rm C} = 1 \text{ A}$ $I_{\rm C} = 1.5 \text{ A},$		2 2.5		2 2.5		6.5 10		6.5 10	v
VCE(sat)	Collector-emitter saturation voltage	5	$\begin{aligned} I_{I} &= 625 \ \mu A, \\ I_{I} &= 935 \ \mu A, \\ I_{I} &= 1.25 \ m A, \\ I_{I} &= 2 \ m A, \\ See \ Note \ 3 \\ I_{I} &= 2.25 \ m A, \end{aligned}$	$I_{C} = 750 \text{ mA}$ $I_{C} = 1 \text{ A}$ $I_{C} = 1.25 \text{ A},$		1.1 1.2 1.3 1.4		1.1 1.2 1.3		1.1 1.2 1.3 1.4		1.1 1.2 1.3	v
IR	Clamp-diode reverse current	6	$\begin{aligned} \eta &= 2.25 \text{ mA}, \\ \text{See Note 3} \\ \hline V_{\text{R}} &= 50 \text{ V}, \\ \hline V_{\text{R}} &= 50 \text{ V}, \\ \hline V_{\text{R}} &= 80 \text{ V}, \\ \hline V_{\text{R}} &= 80 \text{ V}, \end{aligned}$	$T_A = 70 ^{\circ}C$		50 100		1.5 50		50 100		1.5 50	μΑ
VF	Clamp-diode forward voltage	7	I <sub>F</sub> = 1 A I <sub>F</sub> = 1.5 A,	See Note 3		1.75 2		1.75		1.75		1.75	v

# electrical characteristics at 25 °C free-air temperature (unless otherwise noted)

NOTE 3: These parameters must be measured on one output at a time using pulse techniques,  $t_W$  = 10 ms, duty cycle  $\leq$  10%.



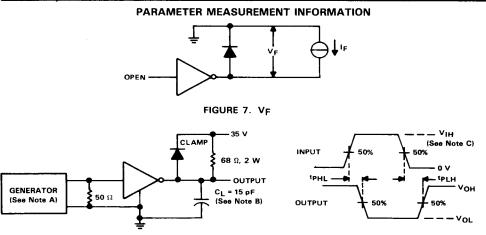
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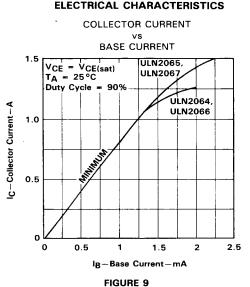
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- B. CL includes all probe and stray capacitance.
  - C.  $V_{IH} = 2.5$  V for ULN2064 and ULN2065.  $V_{IH} = 10$  V for ULN2065 and ULN2067.

FIGURE 8. SWITCHING TIMES

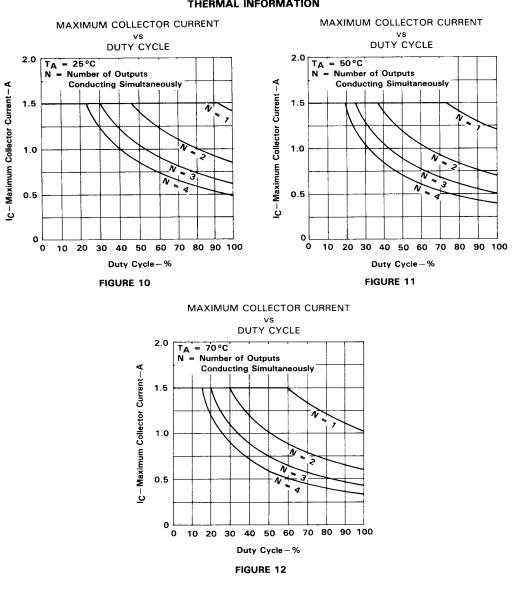




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NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR = 50 kHz, duty cycle = 10%,  $Z_0 = 50 \Omega$ .

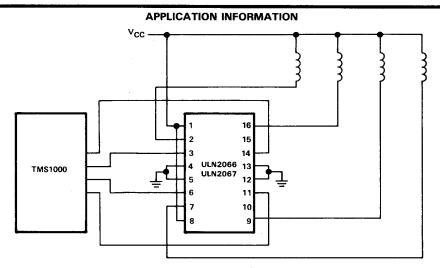
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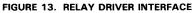


THERMAL INFORMATION



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